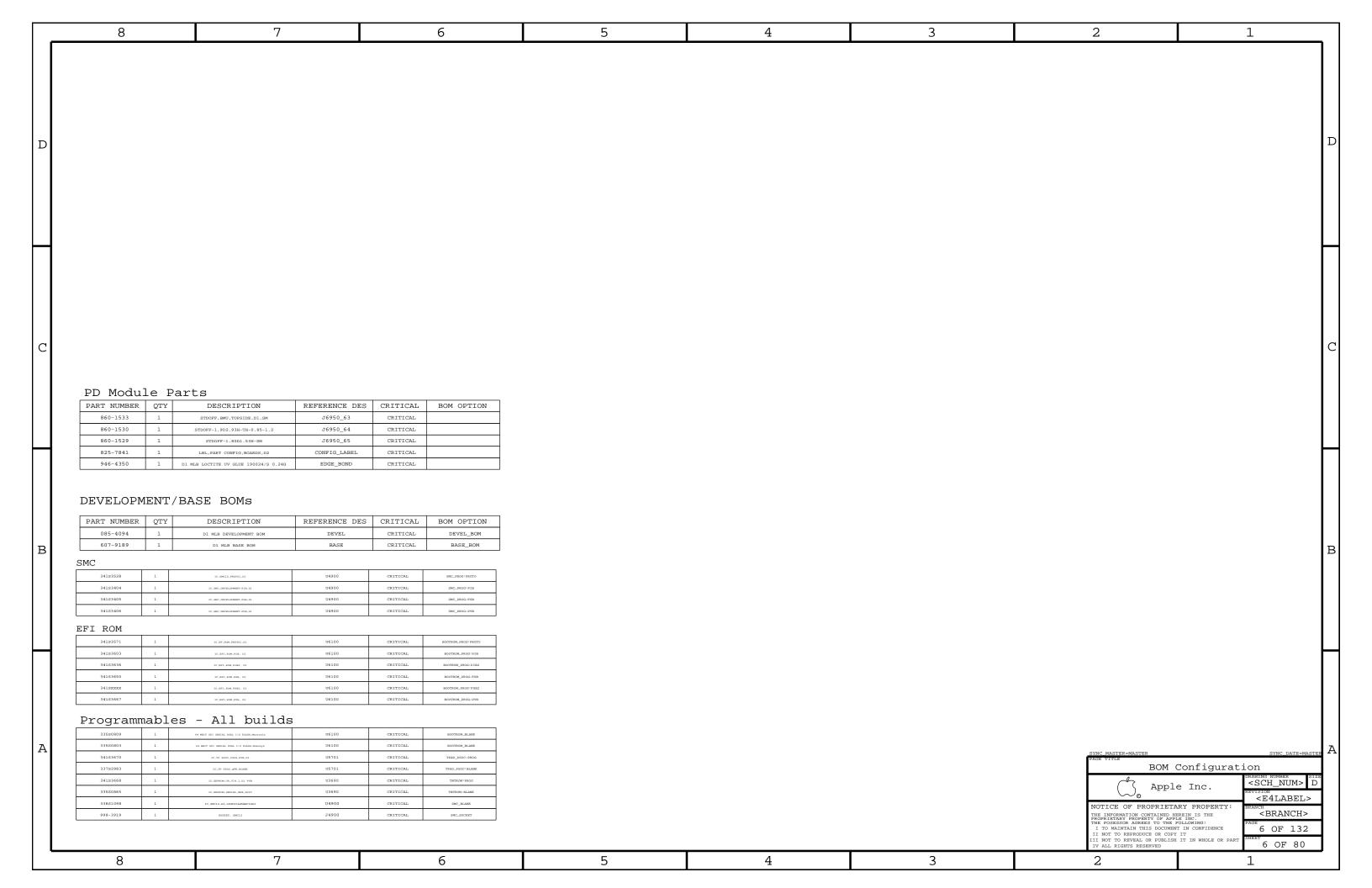
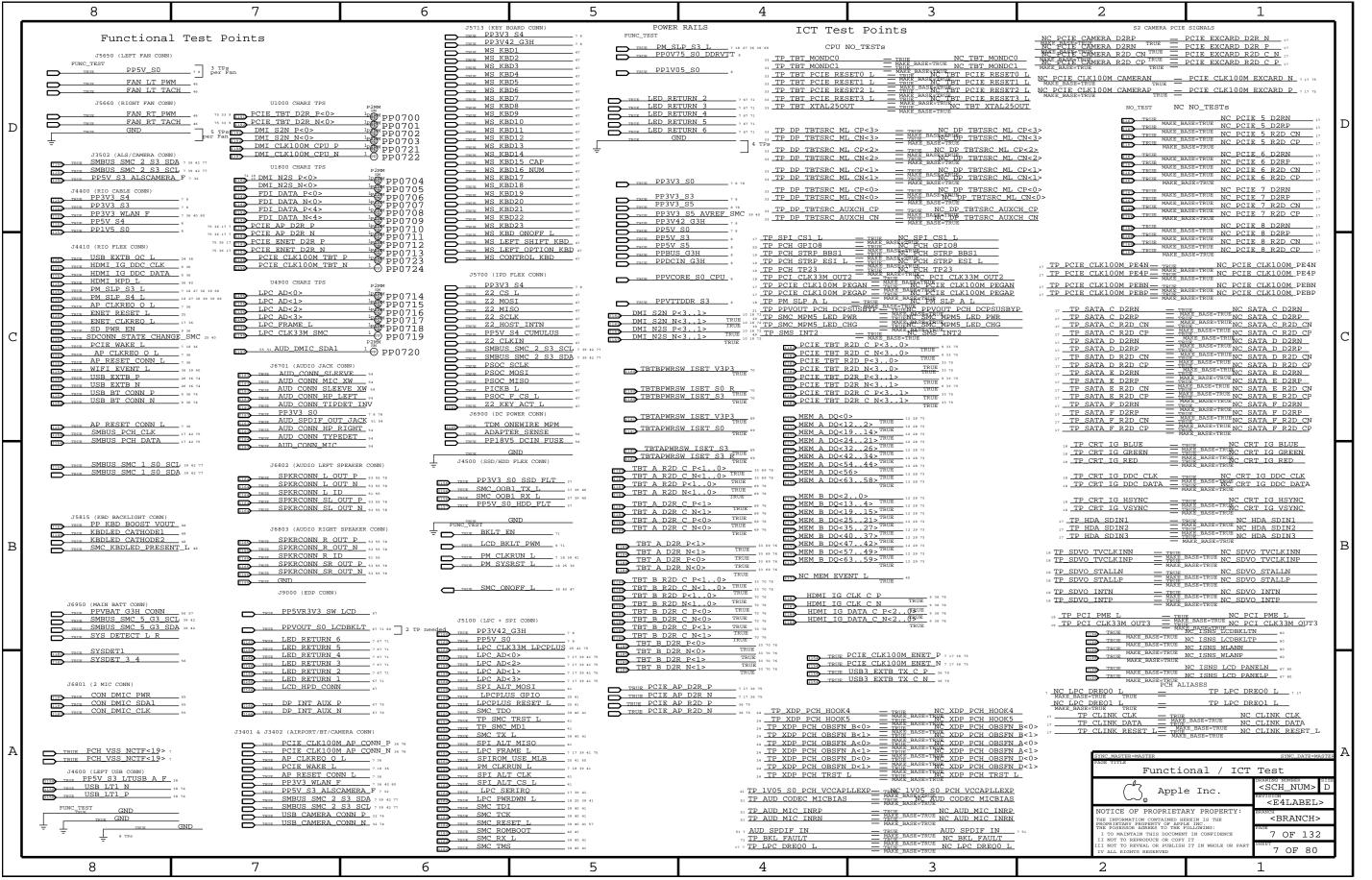


8 7 BOM Variants				6				5 4 3 Bar Code Labels / EEE #'s					2		1			
											•	71townsto D						
BOM NUMBER					BOM OPTIONS				Bar code labels / BBB # B					Alternate Parts PART NUMBER ALTERNATE FOR BOM OPTION REF DES COMMENTS:				
085-4094			BOM,MLB,D1			D1_DEVEL: PVB			PART NUMBER QTY	DESCRIPTION	REFERENCE DES		BOM OPTION		PART NUMBER		COMMENTS:	
607-9189			S,PCBA,MLB,D1			D1_COMMON			826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:DV7Q]	CRITICAL	EEEE: DV7Q	128S0364	128S0264	ALL	Kemet alt to Sanyo	
639-3288			G,SS 6GB,MLB,D1 G,SS 6GB,MLB,D1			B_2C_2.5G, PCH_C1, EEEE: DWP2, F			826-4393 1 826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:DWNY]	CRITICAL	EEEE: DWNY	128S0303 376S0953	128S0353 376S0958	ALL	Panasonic alt to Sanyo RENESAS ALT TO FAIRCHILD	
639-3290			HYNIX 6GB,MLB,D1			_IVB_2C_2.5G,PCH_C1,EEEE:DWN1,E		100,000,00	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:DWP0]	CRITICAL	EEEE: DWP0	12880311	128S0329	ALL	NEC ALT TO SANYO	
639-3291	PCBA,2.9G,HYNIX 6GB,MLB,Dl				DEVEL_BOM, BASE_BOM, CPU_IVB_2C_2.9G, PCH_C1, ERER: DWNW, RAM_6G_HYNIX_CH0_1600_S				826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:DWP2]	CRITICAL	EEEE: DWP2	353s3237	353S2192	ALL	TI ALT TO INTERSIL	
639-3694	PCBA,2.5G,SS 8GB,MLB,D1				DEVEL_BOM, BASE_BOM, CPU_IVB_2C_2.5G, PCH_C1, EEEE: F16P, RAM_4G_SAMSUNG_35NM_1600_S				826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F16M]	CRITICAL	EEEE:F16M	376S0977	376s0859	ALL	Diodes alt to Toshiba	
639-3695		PCBA,2.9	G,SS 8GB,MLB,D1		DEVEL_BOM, BASE_BOM, CPU_1	VB_2C_2.9G,PCH_C1,EEEE:F16F	4,RAM_4G_SAMSUNG_35NM_160	0_s	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F16N]	CRITICAL	EEEE:F16N	13880722	138S0691	ALL	Multi alt to Samsung	
639-3696		PCBA,2.9G,	HYNIX 8GB,MLB,D1		DEVEL_BOM, BASE_BOM, CPU_IVB_2C_2.9G, PCH_C1, EEEE:F16N, RAM_4G_HYNIX_1600_S				826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F16P]	CRITICAL	EEEE:F16P	19780487	19780485	ALL	Epson alt to TXC	
639-3697		PCBA, 2.5G,	HYNIX 8GB,MLB,D1		DEVEL_BOM, BASE_BOM, C	PU_IVB_2C_2.5G,PCH_C1,EEEE:	F16V,RAM_4G_HYNIX_1600_S		826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F16V]	CRITICAL	EEEE:F16V	197s0484	19780485	ALL	NDK alt to TKC	
639-3773		PCBA,2.5G,ELPIDA 6GB,MLB,D1 PCBA,2.9G,ELPIDA 6GB,MLB,D1			DEVEL_BOM, BASE_BOM, CPU_IVB_2C_2.5g, PCH_C1, EEEE: F26M, RAM_6G_ELPIDA_ DEVEL_BOM, BASE_BOM, CPU_IVB_2C_2.9g, PCH_C1, EEEE: F26J, RAM_6G_ELPIDA_1				826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F26H]	CRITICAL	EEEE:F26H	19780479	197S0486	ALL	Epson alt to TXC	
639-3772								_S	826-4393 1 826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F26J]	CRITICAL	EEEE: F26J	19780478	19780486	ALL	NDK alt to TXC	
639-3770			A,2.5G,ELPIDA 8GB,MLB,D1 A,2.9G,ELPIDA 8GB,MLB,D1		DEVEL_BOM, BASE_BOM, CPU_IVB_2C_2.5G, PCH_C1, EEEE:F26L, RAM_4G_ELPIDA_1600_s DEVEL_BOM, BASE_BOM, CPU_IVB_2C_2.9G, PCH_C1, EEEE:F26H, RAM_4G_ELPIDA_1600_s				826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F26L]	CRITICAL	EEEE:F26L EEEE:F26M	197S0481 376S0972	197S0480 376S0612	ALL	Epson alt to NDK ROHM alt to Toshiba	
639-3849			MICRON 6GB,MLB,D1			IVB_2C_2.5G,PCH_C1,EEEE:F2V		100,000,00	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F2WQ]	CRITICAL	EEEE:F2WQ	376S1053	37680604	ALL	Diodes alt to Fairchild	
639-3848			MICRON 6GB,MLB,D1			IVB_2C_2.9G,PCH_C1,EEEE:F2W		100,000,00	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F2WR]	CRITICAL	EEEE:F2WR	376S1017	376S0612	ALL	ROHM alt to Toshiba	
639-3873		PCBA,2.6G,SS 6GB,MLB,D1			DEVEL_BOM,BASE_BOM,CPU_IVB_2C_2.6G,PCH_C1,EEEE:F33H,RAM_6G_SAMSUNG_35NM_CH0_1600_S				826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F2WT]	CRITICAL	EEEE:F2WT	13880624	138S0677	ALL	Murata alt to Taiyo Yuden	
639-3874		PCBA,2.8	G,SS 6GB,MLB,D1	D	EVEL_BOM,BASE_BOM,CPU_IVE	_2C_2.8G,PCH_C1,EEEE:F33P,F	RAM_6G_SAMSUNG_35NM_CH0_1	600_S	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F2WV]	CRITICAL	EEEE:F2WV	138\$0681	13850638	ALL	Taiyo Yuden alt to Samsung	
639-3875		PCBA, 2.6G,	HYNIX 6GB,MLB,D1		DEVEL_BOM,BASE_BOM,CPU	_IVB_2C_2.6G,PCH_C1,EEEE:F3	3L,RAM_6G_HYNIX_CH0_1600	_s	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F336]	CRITICAL	EEEE:F336	152S1703	15281701	ALL	Sumida alt to Cyntec	
639-3876			HYNIX 6GB,MLB,D1			_IVB_2C_2.8G,PCH_C1,EEEE:F3			826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F337]	CRITICAL	EEEE:F337	371S0730	371S0490	ALL	Diodes alt to NXP	
639-3881			G,SS 8GB,MLB,D1			VB_2C_2.6G,PCH_C1,EEEE:F330			826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F338]	CRITICAL	EEEE:F338	13880725	138S0724	ALL	Samsung alt to Murata	
639-3882			G,SS 8GB,MLB,D1			VB_2C_2.8G,PCH_C1,EEEE:F330		0_S	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F339]	CRITICAL	EEEE:F339	13880727	13850709	ALL	Samsung alt to Murata	
639-3884			HYNIX 8GB,MLB,D1			PU_IVB_2C_2.8G,PCH_C1,EEEE:			826-4393 1 826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33C]	CRITICAL	EEEE:F33C EEEE:F33D	376S1080 372S0186	376S0820 372S0185	ALL ALL	Diodes alt to ON Semi	
639-3877			ELPIDA 6GB,MLB,D1			IVB_2C_2.6G,PCH_C1,EEEE:F3:		8	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33F]	CRITICAL	EEEE:F33F	12850363	128S0296	ALL	NEC alt to Sanyo	
639-3878			ELPIDA 6GB,MLB,D1			IVB_2C_2.8G,PCH_C1,EEEE:F3:		100,0000,00	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33G]	CRITICAL	EEEE:F33G	376S0903	37680796	ALL	Fairchild alt to Siliconix	
639-3885			ELPIDA 8GB,MLB,D1		DEVEL_BOM, BASE_BOM, CE	U_IVB_2C_2.6G,PCH_C1,EEEE:	733J,RAM_4G_ELPIDA_1600_S	100,0000,00	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33H]	CRITICAL	EEEE:F33H	740S0144	740S0118	ALL	Littlefuse alt to Polytronic	
639-3886		PCBA,2.8G,	ELPIDA 8GB,MLB,Dl		DEVEL_BOM, BASE_BOM, CE	U_IVB_2C_2.8G,PCH_C1,EEEE:	F33N,RAM_4G_ELPIDA_1600_S		826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33J]	CRITICAL	EEEE:F33J	15281539	152S1598	ALL	Cyntec alt to Toko	
639-3879		PCBA, 2.6G,	MICRON 6GB,MLB,D1		DEVEL_BOM, BASE_BOM, CPU_	IVB_2C_2.6G,PCH_C1,EEEE:F3	BM,RAM_6G_MICRON_CH0_1600	_s	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33K]	CRITICAL	EEEE:F33K	152S1645	152S0461	ALL	Cyntec alt to Vishay	
639-3880		PCBA, 2.8G,	MICRON 6GB,MLB,D1		DEVEL_BOM, BASE_BOM, CPU_	IVB_2C_2.8G,PCH_C1,EEEE:F3	36,RAM_6G_MICRON_CH0_1600	_s	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33L]	CRITICAL	EEEE:F33L	155S0667	155s0583	ALL	MAG LAYERS ALT TO MURATA	
639-3846		PCBA, 2.5G,	MICRON 8GB,MLB,D1		DEVEL_BOM, BASE_BOM, CE	U_IVB_2C_2.5G,PCH_C1,EEEE:	F2WV,RAM_4G_MICRON_1600_S	Total passants (the	826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33M]	CRITICAL	EEEE:F33M	10380305	103S0266	ALL	Yageo alt to Cyntec	
639-3847		PCBA,2.9G,	MICRON 8GB,MLB,Dl		DEVEL_BOM,BASE_BOM,CE	U_IVB_2C_2.9G,PCH_C1,EEEE:	F2WQ,RAM_4G_MICRON_1600_S		826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33N]	CRITICAL	EEEE:F33N	112S0274	112S0254	ALL	Yageo alt to Cyntec	
639-3887		PCBA, 2.6G,	MICRON 8GB,MLB,D1		DEVEL_BOM,BASE_BOM,CE	U_IVB_2C_2.6G,PCH_C1,EEEE:	F33K,RAM_4G_MICRON_1600_S		826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33P]	CRITICAL	EEEE:F33P	376S1113	376S1110	ALL	Diodes to AOS	
639-3888 Mod11	Daret		MICRON 8GB,MLB,D1		DEVEL_BOM, BASE_BOM, CE	U_IVB_2C_2.8G,PCH_C1,EEEE:			826-4393 1	LBL,P/N LABEL,PCB,28MM X 6 MM	[EEEE:F33Q]	CRITICAL	EEEE:F33Q	15580588	155S0367	ALL	murata ALT TO MURATA	
	Per logy December Description Description			REFERENCE D	D1 BOM GR					DOM ODITIONS			500,0000,000					
PART NUMBE	7		U1000					BOM OPTIONS ALTERNATE, COMMON, D1_COMMON1, D1_COMMON2, D1_PROGPARTS, D1_PVB										
33754182 33754292	1	1 IVM, OBPO, KR2, KO, 2. 6, 26W, 2-2, 1. 05, 4M, BOA		U1000	CRITICAL	CPU_IVB_2C_2.6G_RS2	D1_COMMON1		CPUMEM:S0.SMC D	EBUG_YES,TBTBST:Y,TBTRTR:B1,TBTHV:P15V,HUB_2		ASE2.TBTISNS:YES	hana, manata, Jiha					
	1	+	,L1,2.5,35N,2+2,1.1,3M,RGA	U1000	CRITICAL	CPU_IVB_2C_2.5G_QS	D1_COMMON2			35, LPCPLUS_CONN:YES, LPCPLUS_R:YES, CAPS:INT, BTE			Transportation (Inter-					
337S4300	1	IVB, QC96, QS	,L1,2.6,35W,2+2,1.2,3M,BGA	U1000	CRITICAL	CPU_IVB_2C_2.6G_QS	D1_PVB			LOADISNS:NO,LCDBKLT:PROD,KBD	DBKLT: PROD							
337S4302	1	IVB,QC94,QS	IVB,QC94,QS,L1,2.8,35W,2+2,1.2,3M,8GA	U1000	CRITICAL	CPU_IVB_2C_2.8G_QS	D1_PROGPARTS		SMC_PROG: PVB.TETROM: PROG.BOOTROM_PROG: PVB.TPAD_PSOC: PROG									
337S4294	1	IVB,QC4M,QS,	L1,2.9,35W,2+2,1.25,4M,RGA	U1000	CRITICAL	CPU_IVB_2C_2.9G_QS	D1_BLANK						to the processing of the					
337S4264	1	IVB, S RONO, PR	Q,L1,2.5,35W,2+2,1.1,3M,BGA	U1000	CRITICAL	CPU_IVB_2C_2.5G	D1_DEVEL: ENG		ALTERNA	TE,IVB_PPT_XDP,LOADISNS:YES,S0PGOOD_ISL,DDRVR	EF_DAC,VREFDQ:M1_M3,VREFCA	:LDO_DAC	team, manates, class					
337S4338	1	IVB,S ROMY,PR	Q, L1, 2.6, 35W, 2+2, 1.2, 3M, BOA	U1000	CRITICAL	CPU_IVB_2C_2.6G	D1_DEVEL: PVB			ALTERNATE, IVB_PPT_XDP, VREFDQ:M1_	M3, VREFCA: LDO							
337S4339	1	IVB,S ROMU,PR	Q,L1,2.8,35M,2+2,1.2,3M,BGA	U1000	CRITICAL	CPU_IVB_2C_2.8G	IVB_PPT_XDP			XDP,XDP_CONN,XDP_CPU:BPM,>	IDP_PCH							
337S4265	1			U1000	CRITICAL				PINGS BOM OPTIONS 4g_HYNIX_1600_s,ramcfg3:L,ramcfg1:L,ramcfg0:L									
33754180	1			U1800		PCH_ES2	BOM GROUP											
33784235	1		,PPT-MB SPF,P-QS,CO	U1800	CRITICAL	PCH_C0	RAM_4G_HYNIX_160											
337S4283 338S1113	1		2,PPT-MB SFF,PRQ,C1 C,B1,PRQ,288PCBGA,12X12MM	U1800	CRITICAL	PCH_C1 TBTRTR:B1	RAM_2G_ELPIDA_160 RAM_4G_SAMSUNG_28NM_			_ELPIDA_1600_S,RAMCFG3:L,RAMCFG2: MSUNG_28NM_1600_S,RAMCFG3:L,RAMCE			tonic promote, pro-					
33350623	16						2G_MICRON_1600_S,RAMCFG3:L,RAMCFG2:L,RAMCFG0:H											
33380622	16	IC, SDRAM, 20R	IT, 256MK8, DDR3-1600, 78PRGA 02003, 02003, 02003	820, U2+33, U2+46, U2+46, U2+46, U2+70, U3109, U3116, U312	0,0310,03140,03140,03140,034 CRITICAL	2G_HYNIX_1600_S	RAM_4G_ELPIDA_160	0_S		_ELPIDA_1600_S,RAMCFG3:L,RAMCFG2:			Section (Assessed Contraction)					
33350628	16	IC,SDRAM,DDR3-16	500,256MX8,78PBGA,D-DIR,ELPIDA 00000,00000,00	8 30,02833,02848,02860,02866,02870,03130,03116,0313	0,03130,03140 03150,03160,03 CRITICAL	2G_RLPIDA_1600_S	RAM_4G_SAMSUNG_35NM_	1600_S	4G_SA	MSUNG_35NM_1600_S,RAMCFG3:L,RAMCF	FG2:H,RAMCFG1:L,RAM	CFG0:H	Territ, Section (1907)					
33380649	16	IC,SDRAM,DDR	3-1600,256MC8,78PRGA,MICRON 02003,02003,02	020, 02033, 02046, 02060, 02060, 02070, 03120, 03116, 03120	5,0338,03160,03160,03160,03 CRITICAL	2G_MICRON_1600_S	RAM_6G_SAMSUNG_35NM_CH	0_1600_S	6G_SAMS	UNG_35NM_CH0_1600_S,RAMCFG3:L,RAM	MCFG2:H,RAMCFG1:H,F	AMCFG0:L						
33380625	16	IC, SDRAM, DDR	:3-1600,512MXR,7RFRGA,HYNIX 02003,02018,02	020, U2033, U2048, U2048, U2048, U2070, U3139, U3118, U312	0,03130,03140 03150,03160,031 © RITICAL	4G_HYNIX_1600_S	RAM_4G_MICRON_160	0_S	4G	MICRON_1600_S,RAMCFG3:L,RAMCFG2:	H,RAMCFG1:H,RAMCFG	0:H	tone, process, pro-					
33380629	16	IC, SDRAM, DDR3-14	500,512MXR,78FBGA,B-DIR,RLPIDA 00000,00000,00	020,02033,02046,02046,02046,02070,03100,03116,03126	0,03130,03140,03140,03140,034 CRITICAL	4G_ELPIDA_1600_S	RAM_6G_MICRON_CH0_1	600_S	6G_M	ICRON_CH0_1600_S,RAMCFG3:H,RAMCFC	G2:L,RAMCFG1:L,RAMC	FG0:L						
33380624	16	IC,SDRAM,DDR2-1	600, 512HXR, 78FBGA, D35, SAMSUNG 03400, 03400, 03400	030,02033,02048,02040,03046,03070,03130,03116,03130	, 03336, 03160 03160, 03160, 03 GRITICAL	4G_SAMSUNG_35NM_1600_S	RAM_6G_ELPIDA_CH0_1	600_S	6G_E	LPIDA_CH0_1600_S,RAMCFG3:H,RAMCFC	32:L,RAMCFG1:H,RAMC	FG0:L	1000,00000,000					
33380623	8		IT,256MX8,DDR3-1600,78FRGA	U3100,U3110,U3120,U3130,U3140,U3140,U3160,U3160	CRITICAL CRITICAL	6G_SAMSUNG_35NM_CHO_1600_S	RAM_6G_SAMSUNG_28NM_CE			UNG_28NM_CH0_1600_S,RAMCFG3:H,RAM								
33380624	8		600, 512MXR, 78PRGA, D35, SAMSUNG	02000, 02010, 02020, 02030, 02042, 02042, 0204		6G_SAMSUNG_35NM_CH0_1600_S	RAM_6G_HYNIX_CH0_1			IYNIX_CH0_1600_S,RAMCFG3:H,RAMCFG			tana, manata, man	s	YNC_MASTER=MASTER		SYNC_DATE	
333S0622 333S0625	8 IC, SDRAM, 20RIT, 256MKR, DDR3-1600, 78FROA 8 IC, SDRAM, EDR3-1600, 512MKR, 78FROA, WYNIX						RAM_2G_SAMSUNG_1600_S RAM_2G_HYNIX_1600_S		2G_SAMSUNG_35NM_1600_S,RAMCFG3:H,RAMCFG1:L,RAMCFG0:H 2G_HYNIX_1600_S,RAMCFG3:H,RAMCFG1:H,RAMCFG0:L				BOM Configuration					
333S0625 333S0628	8			02400 ,02810 ,02820,02830 ,02862 ,02462 ,02660	, costs CRITICAL CRITICAL CRITICAL	6G_HYNIX_CHO_1600_S	Module F				II, AAMERGI • FI, KAMERG	, • 11		F	_0_	comingu	DRAWING NUMBER	
333S0628 333S0629	8		500,256MX8,78PBGA,D-DIR,RLPIDA 500,512MX8,78PBGA,B-DIR,RLPIDA	U3100, U3110, U3120, U3110, U3140, U3160, U3160	, ULL TO CRITICAL CRITICAL CRITICAL	6G_ELPIDA_CHO_1600_S 6G_ELPIDA_CHO_1600_S	PART NUMBER	QTY	DESCRIPTION	REFERENCE DES CRITICA	L BOM OPTION			1	(Ap	pple Inc.	<sch_num revision<="" td=""></sch_num>	
333S0629 333S0660	16		500, 512MXR, 78FBGA, R-DIR, KLPIDA 2-1600, 512MXR, 78FBGA, MICRON 02000, 02018,02	02000,00910,00020,00010,00009,00000,0000		6G_ELPIDA_CH0_1600_S 4G_MICRON_1600_S	333S0642	16	IC, SDRAM, DDR2-1600, 5129KR, 789RRA, C-DIR, SAMSUNG visos,	REFERENCE DES CRITICA 00010, 20020, 00010, 00040, 00040, 00040, 00020, 00010,	4G_SAMSUNG_28NM_1600_			L	~ @		<e4labe< td=""></e4labe<>	
33380660	8		2-1600 ,512MXR, 78FRGA, MICRON 02000,02010,020	020, U2833, U28462, U28663, U28663, U29703, U31233, U31162, U3126 U3100, U31103, U31205, U31103, U31403, U31603, U31605		4G_MICRON_1600_S 6G_MICRON_CH0_1600_S	33380642	8	IC, SDRAM, DDR2-1600, 512MX8, 78FRGA, C-DIR, SAMSUNG 03000, IC, SDRAM, 2GRIT, 256MX8, DDR2-1600, 78FRGA	00000_00000_00000_00000_00000_00000_0000	4G_SAMSUNG_28NM_1600_ 6G_SAMSUNG_28NM_CHO_160				NOTICE OF PROPR THE INFORMATION CONTAI		TY: BRANCH	
33350660	8		2-1600, 256MCM, 7MPMCDA, MICHON 2-1600, 512MCS, 78PMCDA, MICHON	U3100,U3110,U3120,U3130,U3140,		6G_MICRON_CHO_1600_S	33380642	8	IC, SDRAM, DDR3-1600, 512MKR, 78FFRGA, C-DIE, SAMSUNG	03106,03116,03226,03310,03282,03116,03186,03186 02606,03910,03910,03910,03910,03910,03910 CRITICAL	6G_SAMSUNG_28NM_CHO_160			Т	THE INFORMATION CONTAI PROPRIETARY PROPERTY OF THE POSESSOR AGREES TO I TO MAINTAIN THIS DO	THE FOLLOWING:	PAGE	
	1	1								1				1	I TO MAINTAIN THIS DO II NOT TO REPRODUCE OF II NOT TO REVEAL OR PU	R COPY IT	R PART SHEET	
															IV ALL RIGHTS RESERVED		5 OF 8	
									5			3			2			





PCIE ENET R2D C PCIE ENET R2D C N TRUE PCIE AP R2D C N
PCIE AP D2R P PCIE AP D2R N PCIE AP D2R PI P

PCIE AP D2R PI N

TRUE

PCIE AP D2R PI N

TRUE

TRUE PCIE AP R2D PI P PCIE AP R2D PI N TRUE PCIE CLK100M PCH P

PCIE CLK100M PCH N

PCIE CLK100M TBT P

PCIE CLK100M TBT N

TRUE

TRUE PCH CLK100M SATA P PCH CLK33M PCIIN TRUE PCIE CLK100M SSD P

PCIE CLK100M SSD N TRUE
PEG CLK100M P TRUE
PEG CLK100M P TRUE PEG CLK100M N PEG CLK100M N TRUE
PCIE CLK100M ENET N TRUE
PCIE CLK100M AP P TRUE
PCIE CLK100M AP N TRUE
PCIE CLK100M AP N TRUE
PCIE CLK100M FW P TRUE
PCIE CLK100M FW N TRUE
PCIE CLK100M FW D TRUE
PCIE CLK100M FW N TRUE
PCIE CLK100M EXCARD TRUE
PCIE CLK100M EXCARD TRUE SATA HDD R2D RDRIN P
SATA HDD R2D RDRIN NTRUE
SATA HDD D2R RDROUT TSUE
SATA HDD D2R RDROUT TSUE SATA HDD D2R RDROUT TRUE SATA HDD D2R RDRIN PRUE SATA HDD DZR RDRIN ROUE
SATA HDD DZR RDRIN ROUE
SATA HDD RZD RDROUT TUE
SATA HDD DZR RDRIN PRUE SATA HDD R2D RC P TRUE SATA HDD R2D C P

SATA HDD R2D C N

SATA HDD D2R P

SATA HDD D2R P TRIIE SATA HDD D2R N TRUE
TRUE SATA SSDRHDD D2R P
SATA SSDRHDD D2R N TRUE
SATA SSDRHDD R2D P TRUE
SATA SSDRHDD R2D N TRUE SATA SSDRHDD R2D N USB3 EXTA RX F P

USB3 EXTA RX F N TRUE

USB3 EXTA RX P TRUE USB3_EXTA_RX_N USB3 EXTA TX C P

USB3 EXTA TX C N TRUE

USB3 EXTA TX N TRUE USB3 EXTB RX RC P

USB3 EXTB RX RC N

TRUE

USB3 EXTB RX P

TRUE USB3 EXTB RX N

